

Application No. 10/026,125

Atty Docket No. MXIC 1517-1

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In the Specification:

Please amend paragraph 14 on page 4 as follows:

[0014] FIG. 3 adds an additional bake ~~[[311]]~~ 312, following the pre-erase 211. This bake should be under conditions sufficient to diffuse charges added to the floating gate 402 or the ONO layer 412 by the erase. Two different temperature ranges appear to be useful: 80-150 degrees Celsius and 150-250 degrees Celsius. The time required for sufficient effect can readily be determined, without an excessive degree of experimentation.